SN54ABT16245A, SN74ABT16245A 16-BIT BUS TRANSCEIVERS WITH 3-STATE OUTPUTS

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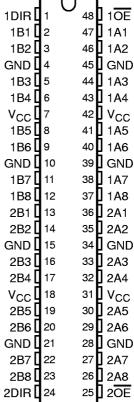
- **Members of the Texas Instruments** Widebus™ Family
- State-of-the-Art *EPIC-IIB™* BiCMOS Design **Significantly Reduces Power Dissipation**
- Typical V_{OLP} (Output Ground Bounce) < 1 V at $V_{CC} = 5 \text{ V}, T_A = 25^{\circ}\text{C}$
- **High-Impedance State During Power Up** and Power Down
- Distributed V_{CC} and GND Pin Configuration **Minimizes High-Speed Switching Noise**
- Flow-Through Architecture Optimizes PCB
- High-Drive Outputs (-32-mA I_{OH}, 64-mA I_{OL})
- Latch-Up Performance Exceeds 500 mA Per **JESD 17**
- ESD Protection Exceeds 2000 V Per MIL-STD-883, Method 3015; Exceeds 200 V Using Machine Model (C = 200 pF, R = 0)
- Package Options Include Plastic Thin Very Small-Outline (DGV), Shrink Small-Outline (DL), and Thin Shrink Small-Outline (DGG) Packages and 380-mil Fine-Pitch Ceramic (WD) Flat Package Using 25-mil **Center-to-Center Spacings**

description

external timing requirements.

The 'ABT16245A devices are 16-bit noninverting 3-state transceivers designed for synchronous two-way communication between data buses. The control-function implementation minimizes

SN54ABT16245A . . . WD PACKAGE SN74ABT16245A . . . DGG, DGV, OR DL PACKAGE (TOP VIEW)



These devices can be used as two 8-bit transceivers or one 16-bit transceiver. They allow data transmission from the A bus to the B bus or from the B bus to the A bus, depending on the logic level at the direction-control (DIR) input. The output-enable (\overline{OE}) input can be used to disable the device so that the buses are effectively isolated.

When V_{CC} is between 0 and 2.1 V, the device is in the high-impedance state during power up or power down. However, to ensure the high-impedance state above 2.1 V, \overline{OE} should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

The SN54ABT16245A is characterized for operation over the full military temperature range of -55°C to 125°C. The SN74ABT16245A is characterized for operation from -40°C to 85°C.



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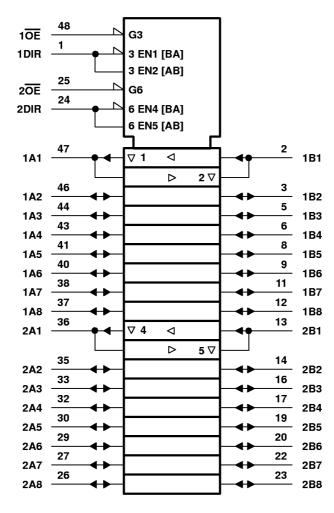


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FUNCTION TABLE (each 8-bit section)

INP	UTS	ODEDATION			
ŌĒ	DIR	OPERATION			
L	L	B data to A bus			
L	Н	A data to B bus			
Н	Χ	Isolation			

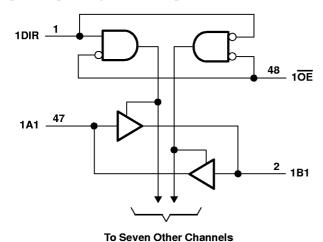
logic symbolt

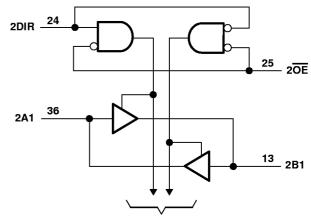


[†] This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.



logic diagram (positive logic)





To Seven Other Channels

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, V _{CC}	–0.5 V to 7 V
Input voltage range, V _I (except I/O ports) (see Note 1)	–0.5 V to 7 V
Voltage range applied to any output in the high or power-off state, VO	–0.5 V to 5.5 V
Current into any output in the low state, IO: SN54ABT16245A	96 mA
SN74ABT16245A	128 mA
Input clamp current, I _{IK} (V _I < 0)	–18 mA
Output clamp current, I _{OK} (V _O < 0)	–50 mA
Package thermal impedance, θ _{JA} (see Note 2): DGG package	89°C/W
DGV package	93°C/W
DL package	94°C/W
Storage temperature range, T _{sta}	. −65°C to 150°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input and output negative-voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

recommended operating conditions (see Note 3)

			SN54ABT	16245A	SN74ABT	UNIT	
			MIN	MAX	MIN	MAX	UNIT
Vcc	CC Supply voltage		4.5	5.5	4.5	5.5	٧
V _{IH}	V _{IH} High-level input voltage		2		2		٧
V _{IL}	Low-level input voltage			0.8		0.8	V
V _I	Input voltage		0	vcc	0	VCC	٧
IOH	High-level output current			-24		-32	mA
loL	Low-level output current			48		64	mA
Δt/Δν	Input transition rise or fall rate Outputs enabled			10		10	ns/V
Δt/ΔV _{CC}	Power-up ramp rate		200		200		μs/V
TA	Operating free-air temperature		-55	125	-4 0	85	°C

NOTE 3: All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.



^{2.} The package thermal impedance is calculated in accordance with JESD 51.

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electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAN	VIETER	TEST CONDITIONS —		T _A = 25°C		SN54ABT1	0245A	SN74ABT16245A		UNIT		
				MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNII	
V _{IK}		V _{CC} = 4.5 V,	I _I = -18 mA			-1.2		-1.2		-1.2	٧	
		V _{CC} = 4.5 V,	I _{OH} = –3 mA	2.5			2.5		2.5			
W		V _{CC} = 5 V,	I _{OH} = –3 mA	3			3		3		V	
VOH		V - 45V	I _{OH} = -24 mA	2			2				V	
		V _{CC} = 4.5 V	I _{OH} = –32 mA	2*					2			
VoL		V _{CC} = 4.5 V	I _{OL} = 48 mA			0.55		0.55			V	
VOL		VCC = 4.5 V	I _{OL} = 64 mA			0.55*				0.55	V	
V _{hys}					100						mV	
C	Control nputs	V _{CC} = 0 to 5.5 V, V	= V _{CC} or GND			±1		±1		±1		
'I A	or B ports	$V_{CC} = 2.1 \text{ V to } 5.5 \text{ V}$ $V_{I} = V_{CC} \text{ or GND}$	V,			±20*		±100		±20	μΑ	
lozpu		$V_{CC} = 0 \text{ to } 2.1 \text{ V},$ $V_{O} = 0.5 \text{ V to } 2.7 \text{ V},$	OE = X			±50**		±50**		±50	μА	
lozpd		$V_{CC} = 2.1 \text{ V to 0},$ $V_{O} = 0.5 \text{ V to 2.7 V},$	OE = X			±50**		±50**		±50	μΑ	
lozH‡		$V_{CC} = 2.1 \text{ V} \text{ to } 5.5 \text{ V}$ $V_{O} = 2.7 \text{ V}, \overline{OE} \ge 2$	V, V			10§		10		10§	μА	
l _{OZL} ‡		$V_{CC} = 2.1 \text{ V to } 5.5 \text{ V}$ $V_{O} = 0.5 \text{ V}, \overline{OE} \ge 2$	V, V			-10§		-10		-10§	μΑ	
loff		V _{CC} = 0,	V_I or $V_O \le 4.5 \text{ V}$			±100				±100	μΑ	
ICEX		V _{CC} = 5.5 V, V _O = 5.5 V	Outputs high			50		50		50	μΑ	
lo¶		$V_{CC} = 5.5 V$,	V _O = 2.5 V	-50	-100	-180	-50	-180	-50	-180	mA	
		V _{CC} = 5.5 V,	Outputs high			2		2		2		
ICC A	or B ports	$I_{O}=0$,	$I_O = 0$, Outpu	Outputs low			32		32		32	mA
		$V_I = V_{CC}$ or GND	Outputs disabled			2		2		2		
	V _{CC} = 5.5 V, One input at 3.4 \	V _{CC} = 5.5 V, One input at 3.4 V, Other inputs at V _{CC} or GND	Outputs enabled			2		1.5		2		
Δlcc#	Data inputs		Other inputs at	Outputs disabled			0.05		1		0.05	mA
I -	Control nputs	V _{CC} = 5.5 V, One input at 3.4 V, Other inputs at V _{CC} or GND				1.5		1.5		1.5		
C: I	Control nputs	V _I = 2.5 V or 0.5 V		_	3						pF	
C _o A	or B ports	V _O = 2.5 V or 0.5 V			6						pF	

^{*} On products compliant to MIL-PRF-38535, this parameter does not apply.



^{**} On products compliant to MIL-PRF-38535, this parameter is not production tested.

 $^{^{\}dagger}$ All typical values are at $V_{CC} = 5 \text{ V}$.

[‡]The parameters IOZH and IOZL include the input leakage current.

[§] This limit may vary among suppliers.

[¶] Not more than one output should be tested at a time, and the duration of the test should not exceed one second.

[#]This is the increase in supply current for each input that is at the specified TTL voltage level rather than VCC or GND.

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switching characteristics over recommended ranges of supply voltage and operating free-air temperature, C_L = 50 pF (unless otherwise noted) (see Figure 1)

		TO (OUTPUT)						
PARAMETER	FROM (INPUT)		V ₍	CC = 5 V 4 = 25°C	' ,	MIN	MAX	UNIT
			MIN	TYP	MAX			
t _{PLH}	A or B	B or A	0.5	2.2	3.4	0.5	4	ns
^t PHL		BULK	0.5	2.3	3.8	0.5	4.6	2
^t PZH	ŌĒ	B or A	0.8	3.6	5.2	0.8	5.5	ns
t _{PZL}		BULK	0.9	3.7	6.1	0.1	7.3	2
[†] PHZ	ŌĒ	B or A	1.3	4.4	5.8	1.3	6.3	ns
[†] PLZ		BOIA	1.4	3.3	4.7	1.4	5.3	110

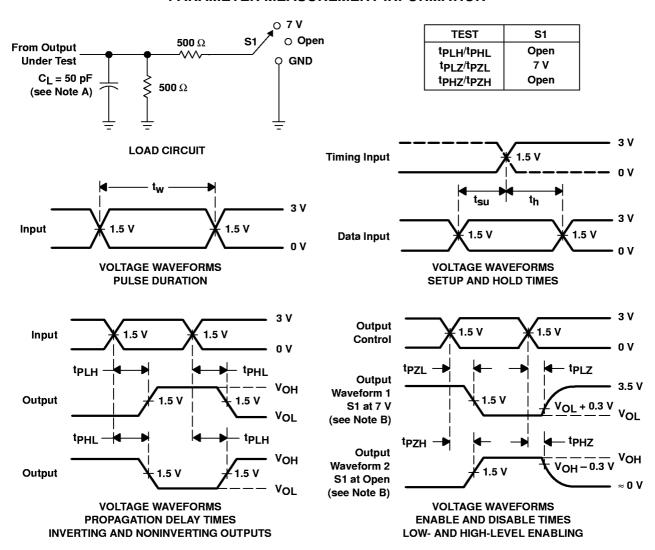
switching characteristics over recommended ranges of supply voltage and operating free-air temperature, C_L = 50 pF (unless otherwise noted) (see Figure 1)

PARAMETER	FROM (INPUT)							
		то (ОИТРИТ)	V _C	CC = 5 V 4 = 25°C	<u>'</u> ,	MIN	MAX	UNIT
			MIN	TYP	MAX			
t _{PLH}	A or B	B or A	1	2.2	3.4	1	3.9	ns
^t PHL		BOIA	1	2.3	3.7	1	4.2	115
^t PZH	ŌĒ	B or A	1	3.6	5.2	1	6.3	ns
tPZL		BULK	1	3.7	5.4	1	6.4	10
^t PHZ	ŌĒ	B or A	2	4.4	5.8	2	6.3	ns
[†] PLZ		BUIA	1.5	3.3	4.7	1.5	5.2	1115



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PARAMETER MEASUREMENT INFORMATION



NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_O = 50~\Omega,~t_f \leq$ 2.5 ns. $t_f \leq$ 2.5 ns.
- D. The outputs are measured one at a time with one transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms

